

FIG. 1

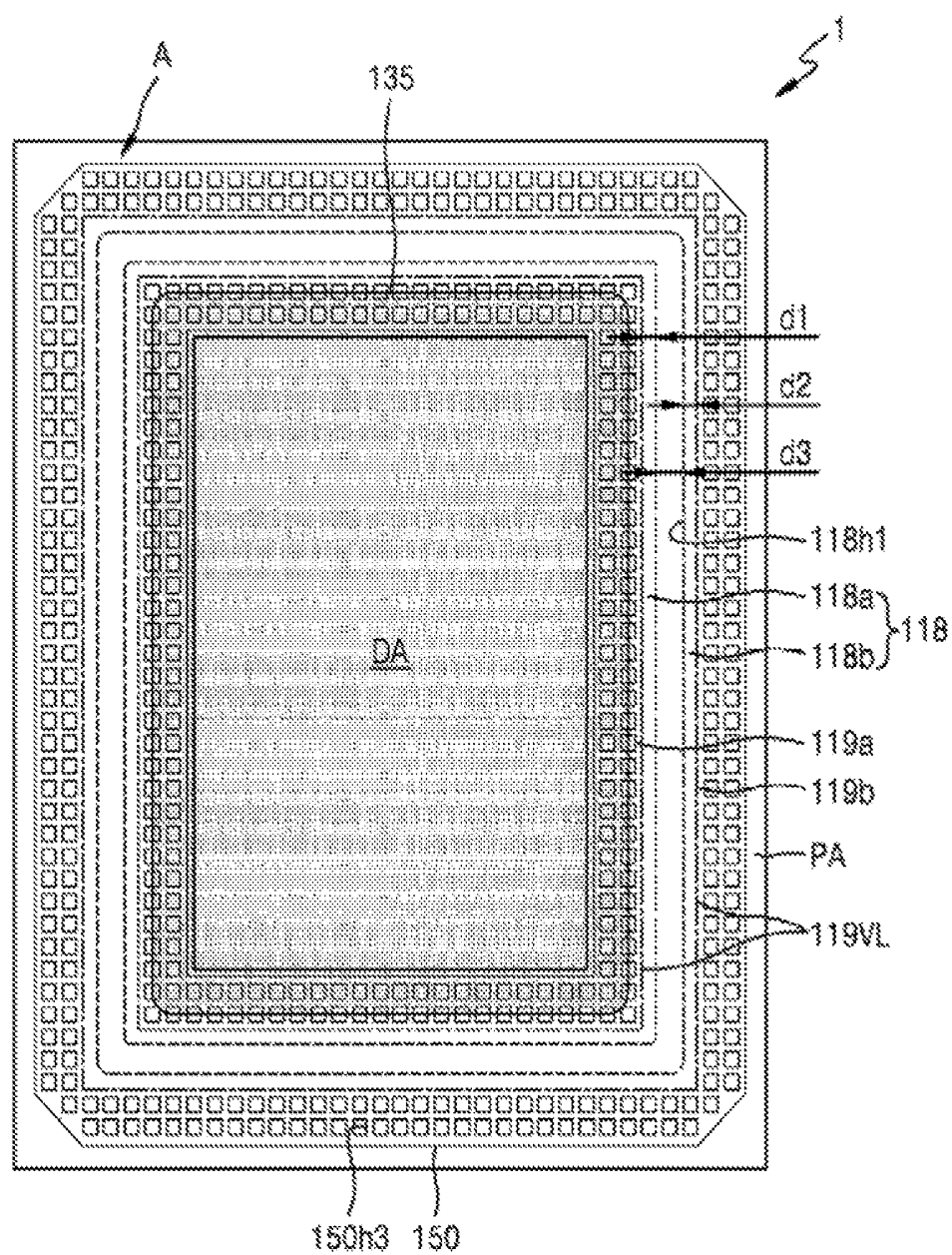


FIG. 2

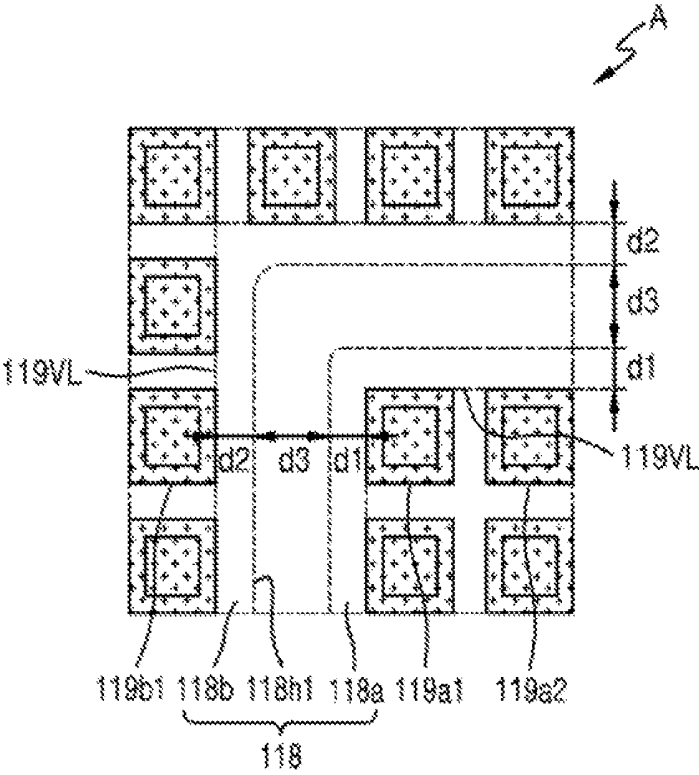


FIG. 3

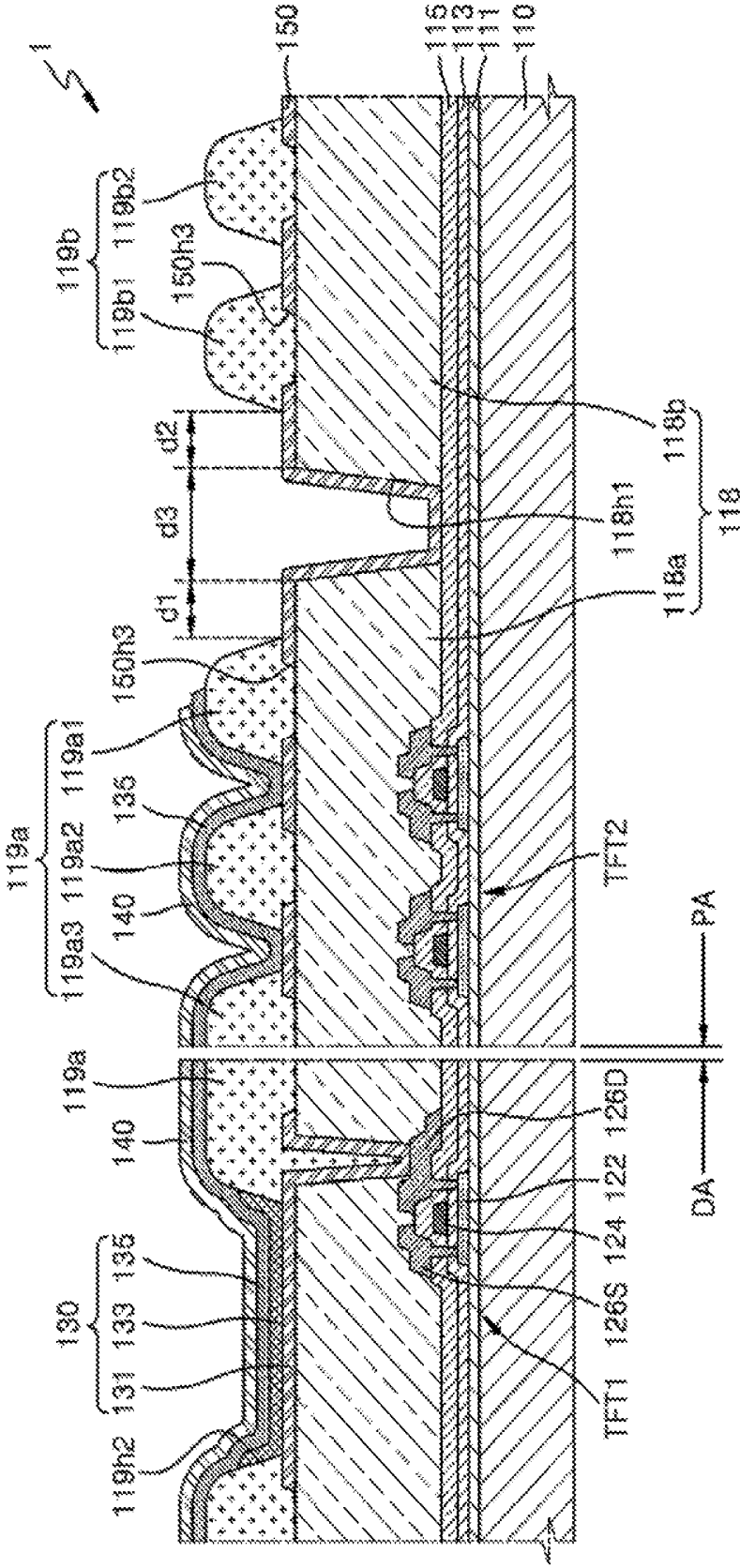


FIG. 5

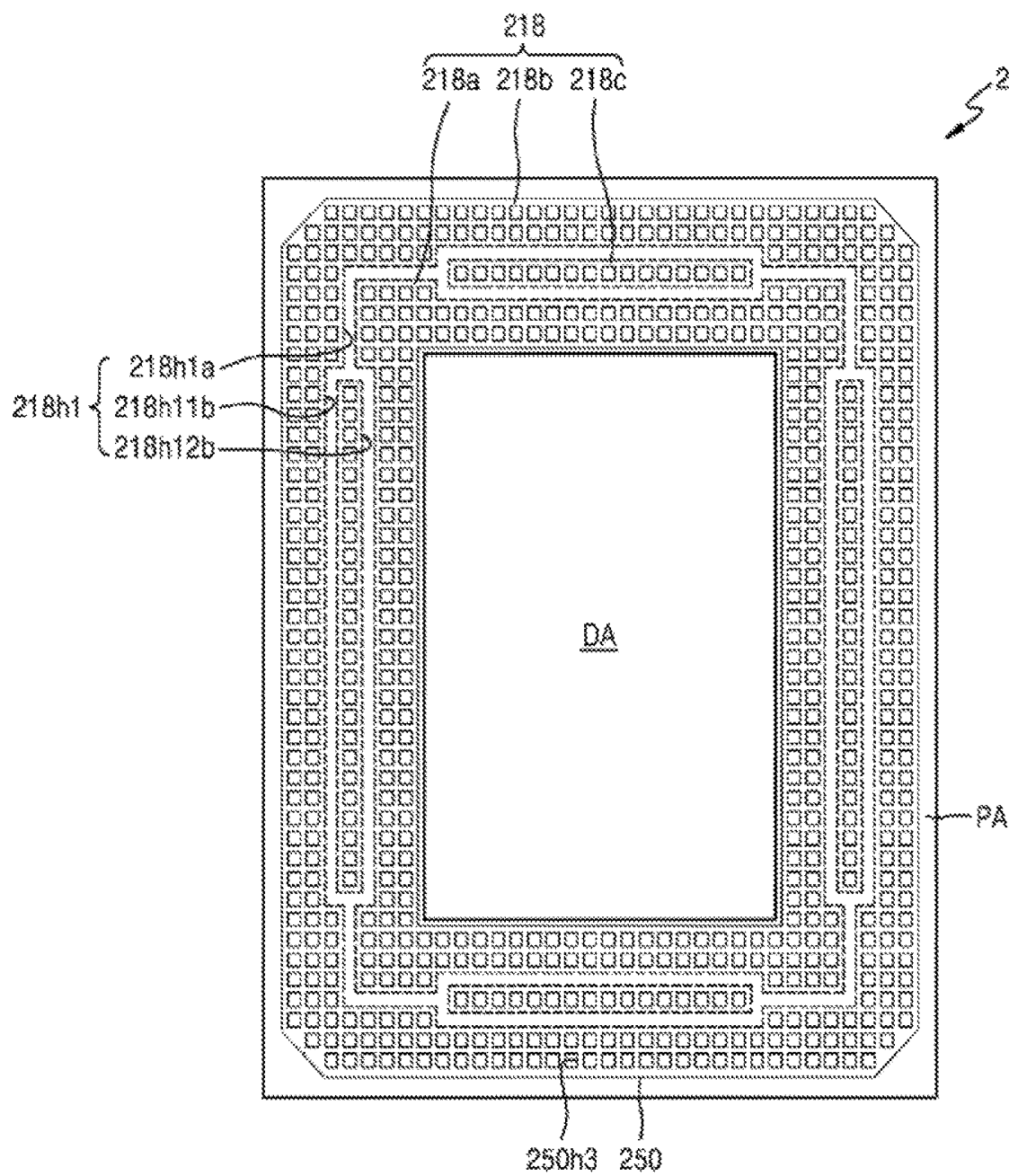
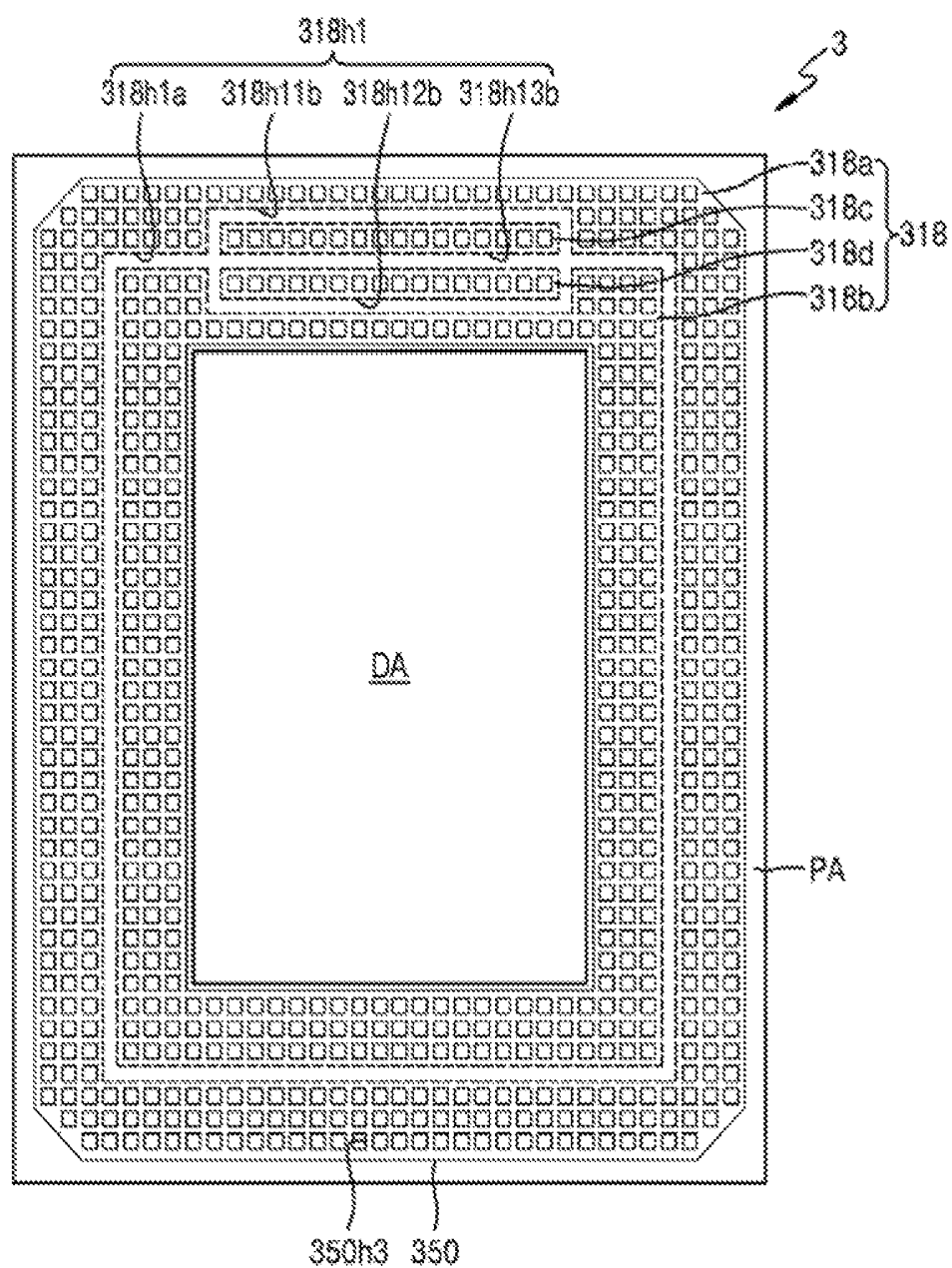


FIG. 7



ORGANIC LIGHT-EMITTING DISPLAY APPARATUS HAVING PROTECTED EMISSION LAYER

CROSS-REFERENCE TO RELATED APPLICATION

[0001] This application is a Division of co-pending U.S. patent application Ser. No. 15,468,991, filed on Mar. 24, 2017, which claims priority to, and the benefit of Korean Patent Application No. 10-2016-0035546, filed on Mar. 24, 2016, in the Korean intellectual Property Office, the disclosures of which are incorporated by reference herein in their entirety.

TECHNICAL FIELD

[0002] One or more embodiments relate to an organic light-emitting display apparatus, and more particularly, to an organic light-emitting display apparatus that may prevent impurities from contaminating an emission layer thereof.

DISCUSSION OF THE RELATED ART

[0003] An organic light-emitting display apparatus includes an organic light-emitting device (OLED). An OLED includes a hole injection electrode, an electron injection electrode, and organic emission layer that is disposed between the hole injection electrode and the electron injection electrode. The electron injection electrode delivers electrons to the organic emission layer while the hole injection electrode delivers holes to the organic emission layer. As the holes and electrons combine within the organic emission layer, excitons are formed. As the excited state of the exciton decays, the energy levels of the electrons relax and photons are emitted. In this way, the OLED is capable of producing light and so OLED displays are able to be self-emission display apparatus that do not require the use of a backlight unit in order to display an image.

[0004] Because the organic light-emitting display apparatus is self-emissive, it can be driven with a low voltage and can be configured to have a light weight and a small size, as compared to display devices that require the use of backlights. Also, because the organic light-emitting display apparatus has a wide viewing angle, high contrast, and a fast response speed, this display technology is a popular choice various types of electronic devices, such as portable media players, mobile phones, and televisions.

[0005] Research into making flexible OLED display apparatuses, such as foldable OLED display apparatuses or rollable OLED display apparatuses has been carried out.

[0006] However, organic light-emitting display apparatuses, according to the related art, have a problem in that impurities, such as gas or moisture, may be introduced from the outside or may be generated in the organic material included in the display apparatus. These impurities may then penetrate into the OLED, either during manufacturing or in use. Penetration of impurities into the MED may then causes deterioration of the quality of an image that is displayed on the OLED display.

SUMMARY

[0007] The or more exemplary embodiments of the present invention include an organic light-emitting display apparatus having a structure in which the quality of an image to

be formed may be prevented from being deteriorated or deterioration may be reduced.

[0008] According to one or more exemplary embodiments of the present invention, an organic light-emitting display apparatus includes a substrate having a display area and a periphery area that is outside of the display area. A first insulating layer is disposed within both the display area and the periphery area. The first insulating layer is disposed over the substrate and has a first opening in the periphery area. A first electrode is disposed within the display area and over the first insulating layer. A first bank is disposed over the first insulating layer in both the display area and the periphery area. The first bank has a second opening through which a center of the first electrode is exposed. A second bank is disposed over the first insulating layer and is separated from the first bank. The first opening is disposed between the first bank and the second bank. An intermediate layer is disposed over the first electrode. A second electrode is disposed over the intermediate layer and the first bank.

[0009] Each of a distance from an edge of the first bank facing the second bank to the first opening and a distance from an edge of the second bank facing the first bank to the first opening may be about 4 μm or more.

[0010] A distance between the first bank and the second bank may be about 15 μm or more.

[0011] The second electrode might not be disposed in the first opening and might not be disposed over the second bank.

[0012] The organic light-emitting display apparatus may further include a conductive layer disposed within the periphery area over the first insulating layer and disposed to cover the first opening.

[0013] The first bank may include a plurality of areas, each separated from one another so that at least a part of the conductive layer is exposed.

[0014] The second electrode may contact the conductive layer between the plurality of areas.

[0015] The conductive layer may include a plurality of third openings disposed within a periphery of the first opening.

[0016] The organic light-emitting display apparatus may further include a second insulating layer disposed under the first insulating layer and including an inorganic material. At least a part of the second insulating layer may be exposed through the first opening.

[0017] The organic light-emitting display apparatus may further include a capping layer disposed over the second electrode in the display area and the periphery area.

[0018] At least a part of the second electrode may be exposed by the capping layer.

[0019] Each of the first insulating layer, the first and second banks, and the capping layer may include an organic material.

[0020] The organic light-emitting display apparatus may further include an encapsulation layer. The encapsulation layer may include at least one inorganic layer and at least one inorganic layer, each disposed over the capping layer.

[0021] The first opening may encompass the display area.

[0022] The first insulating layer may include a first area and a second area separated from each other by the first opening.

[0023] The first opening may include a main opening and a plurality of branched openings branched from the main opening.

[0024] The display area may include four corners and four edges connecting the four corners.

[0025] The main opening may be located adjacent to each of the four corners, and the plurality of branched openings may be located in at least two of the four edges.

[0026] The main opening may be branched into at least three branched openings, and the at least three branched openings may be located in at least one of the four edges.

[0027] The first insulating layer may further include a third area surrounded by the branched openings.

[0028] The organic light-emitting display apparatus may further include a conductive layer in the first area, the second area, and the third area over the first insulating layer. The conductive layer may have a plurality of third openings located in each of the second area and the third area.

[0029] An organic light-emitting display apparatus includes a substrate including a display area in a center thereof and a non-display area surrounding the display area. A first bank is disposed on the substrate. The first bank includes an OLED and a plurality of openings that correspond to a plurality of sub-pixels. A second bank is separated from the first bank and is disposed entirely within the non-display area. An insulating layer covers the first bank and the second bank. The insulating layer has an opening disposed between the first bank and the second bank such that the opening separates the first bank from the second bank.

[0030] The first bank and the same bank may each include a same organic material as the insulating layer. The organic light-emitting display apparatus may further include a first electrode disposed within the display area and overlapping the insulation layer therein. A center of the first electrode may be exposed through an opening in the first bank. The organic light-emitting display apparatus may further include an intermediate layer disposed over the first electrode and a second electrode disposed over the intermediate layer and the first bank.

BRIEF DESCRIPTION OF THE DRAWINGS

[0031] These and/or other aspects will become apparent and more readily appreciated from the following description of the embodiments, taken in conjunction with the accompanying drawings in which:

[0032] FIG. 1 is a plan view schematically illustrating an organic light-emitting display apparatus according to an exemplary embodiment of the present invention;

[0033] FIG. 2 is a plan view schematically illustrating region A of FIG. 1;

[0034] FIG. 3 is a cross-sectional view schematically illustrating a part of the organic light-emitting display apparatus of FIG. 1;

[0035] FIG. 4 is a cross-sectional view schematically illustrating a part of an organic light-emitting display apparatus;

[0036] FIG. 5 is a plan view schematically illustrating a part of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention;

[0037] FIG. 6 is a cross-sectional view schematically illustrating a part of the organic light-emitting display apparatus of FIG. 5; and

[0038] FIG. 7 is a cross-sectional view schematically illustrating a part of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention.

DETAILED DESCRIPTION

[0039] In describing exemplary embodiments of the present disclosure illustrated in the drawings, specific terminology is employed for sake of clarity. However, the present disclosure is not intended to be limited to the specific terminology so selected, and it is to be understood that each specific element includes all technical equivalents which operate in a similar manner.

[0040] Those components that are the same as or similar to other components may be referred to by the same reference numerals throughout the figures, and redundant explanations of these components may be omitted.

[0041] Also, sizes and thicknesses of elements in the drawings may be exaggerated for clarity of illustration and convenience of explanation. Accordingly, exemplary embodiments of the present invention should not be viewed as necessarily being limited to the sizes and thicknesses of the elements, as they appear in the drawings.

[0042] FIG. 1 is a plan view schematically illustrating an organic light-emitting display apparatus according to an exemplary embodiment of the present invention. FIG. 2 is an enlarged plan view of region A of FIG. 1. FIG. 3 is a cross-sectional view schematically illustrating a part of the organic light-emitting display apparatus of FIG. 1, FIG. 4 is a cross-sectional view schematically illustrating a part of an organic light-emitting display apparatus according to an example.

[0043] Referring to FIGS. 1 through 3, an organic light-emitting display apparatus 1 according to an exemplary embodiment of the present invention includes a substrate 110 having a display area DA and a periphery area PA. The periphery area PA is a non-display area that is disposed outside of the display area DA. The substrate 110 may include various materials such as glass, metal, plastic, and the like. According to an exemplary embodiment of the present invention, the substrate 110 may be a flexible substrate. For example, the substrate 110 may include a polymer resin, such as polyethersulphone (PES), polyacrylate (PAR), polyetherimide (PEI), polyethylene naphthalate (PEN), polyethylene terephthalate (PET), polyphenylene sulfide (PPS), polyallylate, polyimide (PI), polycarbonate (PC), or cellulose acetate propionate (CAP).

[0044] The display area DA of the substrate 110 is an area in which an image is displayed. The display area DA may include a plurality of first thin film transistors TFT1 and organic light-emitting devices (OLEDs) 130, which are electrically connected to the plurality of first thin film transistors TFT1. The OLEDs 130 may be electrically connected to the plurality of first thin film transistors TFT1 by a plurality of first electrodes 131. A plurality of second thin film transistors TFT2 may be disposed in the periphery area PA of the substrate 110. The plurality of second thin film transistors TFT2 may be a part of a circuit unit that is configured, for example, for controlling electrical signals that are applied to the display area DA.

[0045] Each of the first thin film transistors TFT1 may include a semiconductor layer 122, a gate electrode 124, a source electrode 126S, and a drain electrode 126D. The semiconductor layer 122 may include amorphous silicon, polycrystalline silicon, or an organic semiconductor material. The gate electrode 124 is disposed above the semiconductor layer 122. The source electrode 126S and the drain electrode 126D are in electrical communication with each other, to an extent that is dictated by signals applied to the

gate electrode **124**. The gate electrode **124** may have a single layer structure or a multi-layered structure. The gate electrode **124** may include one or more of aluminum (Al), platinum (Pt), palladium (Pd), silver (Ag), magnesium (Mg), gold (Au), nickel (Ni), neodymium (Nd), (Ir), chromium (Cr), lithium (Li), calcium (Ca), molybdenum (Mo), titanium (Ti), tungsten (W), and copper (Cu). The precise composition of the gate electrode **124** may be determined, for example, by taking into account adhesion with an adjacent layer, surface flatness of a layer to be stacked, and processability.

[0046] In order to adequately insulate the semiconductor layer **122** from the gate electrode **124**, a gate insulating layer **113** may be disposed between the semiconductor layer **122** and the gate electrode **124**. The gate insulating layer **113** may include an inorganic material, such as a silicon oxide, a silicon nitride and/or a silicon oxynitride. Furthermore, a second insulating layer **115** may be disposed at a top portion of the gate electrode **124**. The source electrode **126S** and the drain electrode **126D** may each be disposed over the second insulating layer **115**. The second insulating layer **115** may include an inorganic material, such as a silicon oxide, a silicon nitride and/or a silicon oxynitride. The source electrode **126S** and the drain electrode **126D** are electrically connected to the semiconductor layer **122** via contact holes that are formed through both the second insulating layer **115** and the gate insulating layer **113**.

[0047] The source electrode **126S** and the drain electrode **126D** may have a single layer structure or a multi-layered structure. The source electrode **126S** and the drain electrode **126D** may each include Al, Pt, Pd, Ag, Mg, Au, Ni, Nd, Ir, Cr, Li, Ca, Mo, Ti, W, and/or Cu. The precise composition of the source electrode **126S** and the gate electrode **126D** may be determined, for example, by taking into account conductivity, etc. An insulating layer including the inorganic material may be formed by chemical vapor deposition (CVD) or atomic layer deposition (ALD).

[0048] A buffer layer **111** may be disposed between the first thin film transistors TFT1 and the substrate **110**. The buffer layer **111** may include an inorganic material, such as a silicon oxide, a silicon nitride and/or a silicon oxynitride. The buffer layer **111** may be used to render a top surface of the substrate **110** more smooth, thereby minimizing or preventing an impurity from the substrate **110**, etc. from penetrating into the semiconductor layer **122** of each of the first thin film transistors TFT1.

[0049] A first insulating layer **118** may be disposed over each of the first thin film transistors TFT1. For example, when the OLEDs **130** are disposed above the first thin film transistors TFT1, the first insulating layer **118** may have a flat top surface on which a first electrode **131** may be flatly formed. The first insulating layer **118** may be formed of an organic material, such as acryl, benzocyclobutene (BCB), polyimide (PI), or hexamethyldisiloxane (HMDSO), for example. In FIG. 3, the first insulating layer **118** has a single layer structure. However, the first insulating layer **118** may alternatively have a multi-layer structure. The first insulating layer **118** may be disposed in the display area DA and the periphery area PA outside the display area DA of the substrate **110**. The first insulating layer **118** may have a first opening **118h1** through which the second insulating layer **115** in the periphery area PA is exposed. The first insulating layer **118** may be physically divided into at least two parts by the first opening **118h1**. This arrangement of the first

insulating layer **118** may prevent an impurity, introduced from the outside, from penetrating into the display area DA through the first insulating layer **118**.

[0050] In the display area DA of the substrate **110**, the OLED **130** is disposed over the first insulating layer **118**. The OLED **130** includes the first electrode **131**, a second electrode **135**, and an intermediate layer **133** disposed between the first electrode **131** and the second electrode **135**. The OLED **110** may also include an emission layer.

[0051] An opening in the first insulating layer **118** exposes either the source electrode **126S** or the drain electrode **126D** of each of the first thin film transistors TFT1. The first electrode **131** contacts either the source electrode **126S** or the drain electrode **126D** through the opening and the first electrode **131** is electrically connected to each of the first thin film transistors TFT1.

[0052] The first electrode **131** may be formed as a semi-transparent or fully-transparent electrode or as a reflective electrode. When the first electrode **131** is formed as a semitransparent or fully-transparent electrode, the first electrode **131** may include a transparent conductive layer. The transparent conductive layer may be an indium tin oxide (ITO), an indium zinc oxide (IZO), a zinc oxide (ZnO), an indium oxide (In₂O₃), an indium gallium oxide (IGO), and/or an aluminum zinc oxide (AZO). For example, in addition to the transparent conductive layer, the first electrode **131** may further include a semi-transmissive layer for increasing light efficiency. The semi-transmissive layer may be a thin film having a thickness of several to several tens of nm and formed of Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, Li, Ca, and/or Yb. When the first electrode **131** is formed as a reflective electrode, the first electrode **131** may include a reflective layer formed of Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, and/or a compound thereof. A transparent conductive layer may be disposed at a top portion and/or a bottom portion of the reflective layer. The transparent conductive layer may include an ITO, an IZO, a ZnO, an indium oxide (In₂O₃), an IGO, and/or are AZO. However, embodiments of the present invention are not limited thereto, and the first electrode **131** may be formed of various materials, and various modifications are possible where the structure of the first electrode **131** may be a single layer structure or a multi-layered structure.

[0053] A first bank **119a** may be disposed over the first insulating layer **118** in the display area DA and the periphery area PA. The first bank **119a** has an opening that corresponds to sub-pixels. For example, at least a center of the first electrode **131** is exposed through a second opening **119h2**. Pixels are thereby defined by the openings. Also, the first bank **119a** may increase a distance between an edge of the first electrode **131** and the second electrode **135** above the first electrode **131**, thereby preventing arcing, and other related problems, from occurring in the edge of the first electrode **131**. The first bank **119a** may be formed of an organic material, such as PI or HMDSO. A second bank **119b** may be disposed over the first insulating layer **118** and may be separated from the first bank **119a**, in the periphery area PA by the first opening **118h1** of the first insulating layer **118**, which is located between the first bank **119a** and the second bank **119b**.

[0054] For example, the first bank **119a** and the second bank **119b** may be completely separated from each other at both sides of the first opening **118h1**. Because the first bank **119a** and the second bank **119b** are completely separated

from each other, an impurity, such as gas or moisture, penetrating into the second bank **119b** is not introduced into the first bank **119a**, regardless of whether the impurity was introduced from the outside or generated within the second bank **119b**. Thus, the impurity may be prevented from penetrating into the display area DA and the quality of an image displayed in the organic light-emitting display apparatus **1** may be prevented from being deteriorated or deterioration may be reduced. The second bank **119b** may be formed of the same material as a material for forming the first bank **119a**. The first and second banks **119a** and **119b** may be formed of the same organic material as that of the first insulating layer **118**. However, embodiments of the present invention are not limited thereto.

[0055] The intermediate layer **133** of the OLED **130** may include a low molecular weight material or a polymer material. When the intermediate layer **133** includes a low molecular weight material, the intermediate layer **133** may have a structure in which a hole injection layer (HIL), a hole transport layer (HTL), an emission layer (EML), an electron transport layer (ETL), and an electron injection layer (EL) are stacked on one another. The intermediate layer **133** may include organic materials, such as, copper phthalocyanine (CuPc), N,N'-Di(naphthalene-1-yl)-N,N'-diphenyl-benzidine (NPB), and/or tris-8-hydroxyquinoline aluminum (Alq3). These layers may be formed by a vacuum deposition method. When the intermediate layer **133** includes a polymer material, the intermediate layer **133** may have a structure including an HTL and an EML. In this case, the HTL may include poly 3,4-ethylenedioxythiophene (PEDOT), and the EML may include a poly-phenylenevinylene (PPV)-based polymer material and a polyfluorene-based polymer material. The intermediate layer **133** may be formed by a screen printing or inkjet printing method, a laser induced thermal imaging (LITI) method, or the like.

[0056] However, the intermediate layer **133** is not limited thereto and may have various alternative structures. The intermediate layer **133** may include a layer formed integrally with a plurality of first electrodes **131** and/or a patterned layer that corresponds to each of the plurality of first electrodes **131**.

[0057] The second electrode **135** may be disposed in the display area DA and the periphery area PA. In particular, the second electrode **135** may be disposed at top portions of the intermediate layer **133** and the first bank **119a**. For example, the second electrode **135** might not be disposed in the first opening **118h1** or over the second bank **119b**. The second electrode **135** may be formed as one body in the plurality of OLEDs **130** and may correspond to the plurality of first electrodes **131**.

[0058] The second electrode **135** may be formed as a semitransparent or fully transparent electrode or as a reflective electrode. When the second electrode **135** is formed as a semitransparent or fully transparent electrode, the second electrode **135** may include Ag, Al, Mg, Li, Ca, Cu, LiF/Ca, LiF/Al, MgAg, and/or CaAg and may include a thin layer having a thickness of between several nm to several tens of nm. When the second electrode **135** is formed as a reflective electrode, the second electrode **135** may be formed of Ag, Al, Mg, Li, Ca, LiF/Ca, LiF/Al, MgAg, and/or CaAg. However, the composition and material of the second electrode **135** are not limited thereto, and various modifications are possible.

[0059] As described above, the first insulating layer **118** and the first bank **119a** are disposed over the substrate **110** in the display area DA and the periphery area PA. The first insulating layer **118** includes the first opening **118h1** located in the periphery area PA. Also, the first bank **119a** is spaced apart from the first opening **118h1** by a predetermined distance d1. The second bank **119b** may be disposed in an opposite direction from which the first bank **119a** is disposed, with respect to the first opening **118h1**, and the second bank **119b** may be spaced apart from the first opening **118h1** by a predetermined distance d2. For example, the first bank **119a** and the second bank **119b** might not be disposed in the first opening **118h1** and may be completely separated from each other.

[0060] A conductive layer **150** may be disposed at a top portion of the first insulating layer **118** and in the first opening **118h1**, which are disposed in the periphery area PA. The conductive layer **150** may be disposed on the same layer as the first electrode **131**. At least a part of the conductive layer **150** may be disposed between the first insulating layer **118** and the first bank **119a** and between the first insulating layer **118** and the second bank **119b**. The conductive layer **150** may be formed of the same material as that of the first electrode **131** and the conductive layer **150** may completely cover the first opening **118h1**.

[0061] According to an exemplary embodiment of the present invention, the conductive layer **150** may include a plurality of third openings **150h3**, each disposed in the periphery of the first opening **118h1**. The first bank **119a** may include a plurality of areas **119a1**, **119a2**, and **119a3**, separated from one another, and disposed in the periphery area PA. The second bank **119b** may also include a plurality of areas **119b1** and **119b2**, separated from one another, and disposed in the periphery area PA. The plurality of areas **119a1**, **119a2**, **119a3**, **119b1** and **119b2** may be disposed to cover an edge of the conductive layer **150** including the plurality of third openings **150h3**. The conductive layer **150** including the third openings **150h3** may have a mesh shape. For example, the plurality of areas **119a1**, **119a2**, **119a3**, **119b1**, and **119b2** of the first and second banks **119a** and **119b** are separated from one another, whereas conductive layers **150** might not be completely separated from one another, and may make some contact with each other via the third openings **150h3**.

[0062] The third openings **150h3** in the conductive layer **150** may be disposed at a bottom portion of the conductive layer **150** and may serve as a path in which a gas generated from the first insulating layer **118**, formed of an organic material, is dissipated to the outside. Thus, the quality of an image formed by the organic light-emitting display apparatus **1** may be prevented from being deteriorated, or deterioration may be reduced, by preventing the gas that is generated from the first insulating layer **118** from penetrating into the display area DA.

[0063] The second electrode **135** may be disposed over the first bank **119a**. The second electrode **135** may contact the conductive layer **150** at spaces between the areas **119a1**, **119a2**, and **119a3** of the first bank **119a**. The conductive layer **150** may be a power line for supplying power to the second electrode **135** or a connection line for connecting the power line for supplying power to the second electrode **135**.

[0064] Referring to FIG. 1, the first opening **118h1** in the first insulating layer **118** may encompass the display area DA. For example, the first opening **118h1** may form a closed

loop that completely surrounds the display area DA. Thus, the first insulating layer 118 may include a first area 118a and a second area 118b that are separated from each other by the first opening 118h1. The first area 118a and the first bank 119a may be disposed in the same direction with respect to the first opening 118h1, and the second area 118b and the second bank 119b may be disposed in the same direction with respect to the first opening 118h1. The second electrode 135 might only be disposed over the first bank 119a and might not be disposed in the first opening 118h1 or over the second bank 119b.

[0065] A capping layer 140 for increasing light efficiency of the organic light-emitting display apparatus 1 may be disposed over the second electrode 135. The capping layer 140 may be disposed within the display area DA and the periphery area PA and may be disposed only at a top portion of the second electrode 135, and might not extend beyond the second electrode 135. For example, at least a part of the second electrode 135 may be exposed by the capping layer 140. The capping layer 140 may be formed of an organic material. Although not shown in FIG. 3 an encapsulation layer (260 of FIG. 6) may be disposed over the capping layer 140, the encapsulation layer including at least one inorganic layer and at least one organic layer.

[0066] As described above, the first bank 119a and the second bank 119b may be disposed at opposite sides of the first opening 118h1. The distance d1, which extends from an edge of the first bank 119a facing the second bank 119b to the first opening 118h1, may be at least 4 μm. Similarly, the distance d2, which extends from an edge of the second bank 119b facing the first bank 119a to the first opening 118h1, may be at least 4 μm. The distances d1 and d2 may either be the same as or different from each other. Reference numeral 119VL of FIGS. 1 and 2 may represent a virtual line that connects edges of the plurality of areas 119a1, 119a2, and 119a3, included in the first bank 119a, and edges of the plurality of areas 119b1 and 119b2, included in the second bank 119b.

[0067] When each of the distances d1 and d2 is less than about 4 μm, the first bank 119a and/or the second bank 119b may flow into the first opening 118h1.

[0068] A width d3 of the first opening 118h1 may be 7 μm or more. For example, a distance between the first bank 119a and the second bank 119b may be about 15 μm or more. Through this configuration, the first bank 119a and the second bank 119b might not be connected to each other within the first opening 118h1.

[0069] Referring to FIG. 4, an organic light-emitting display apparatus 1' according to an example includes a second insulating layer 115' disposed within a periphery area and a first insulating layer 118' disposed over the second insulating layer 115'. The first insulating layer 118' includes a first opening 118h1'. A conductive layer 150' may be disposed in the first opening 118h1'. The conductive layer 150' may include third openings 150h3' formed in the periphery of the first opening 118h1'.

[0070] A first bank 119a' and a second bank 119b', which, together, cover at least a part of the conductive layer 150', may be disposed over the first insulating layer 118'. The first bank 119a' and the second bank 119b' may be connected to each other within the first opening 118h1'. A second electrode 135' may be disposed over the first bank 119a'. The second electrode 135' may contact the conductive layer 150'.

[0071] Because each of the first bank 119a', the second bank 119b' and the first insulating layer 118' are formed of organic materials, impurities G1' and G2' (which may include gas and/or moisture introduced into the second bank 119b') which may be disposed outside of the first opening 118h1' or the first insulating layer 118', or may be generated from the second bank 119b' or the first insulating layer 118', may be introduced into the first bank 119a' via a connection part 119c' disposed within the first opening 118h1' along a path P' shown in FIG. 4. The impurities G1' and G2' (which may include the gas and/or moisture) penetrating into the display area DA may penetrate into the intermediate layer 133 including the EML. Thus, the quality of an image formed in the organic light-emitting display apparatus 1' may be deteriorated.

[0072] Referring back to FIG. 3, the first bank 119a and the second bank 119b are separated from each other at opposing sides of the first opening 118h1. The first bank 119a, the first opening 118h1, the second bank 119b, and the first opening 118h1 may each be spaced apart from one another by the predetermined distance d1 or d2. The distances d1 and d1 may each be, for example, about 4 μm or more. Thus, in spite of a problem related to a process or characteristics of organic materials for forming the first and second banks 119a and 119b, the first and second banks 119a and 119b might not flow into the first opening 118h1.

[0073] Through this configuration, the impurity (e.g. gas and/or moisture) introduced into the second bank 119b or generated in the second bank 119b might not be introduced into the first bank 119a. Thus, the quality of the image formed in the organic light-emitting display apparatus 1 may be prevented from being deteriorated, or may reduce an extent of deterioration, by blocking the impurity from penetrating into the display area DA.

[0074] FIG. 5 is a plan view schematically illustrating a part of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention, and FIG. 6 is a cross-sectional view schematically illustrating a part of the organic light-emitting display apparatus of FIG. 5.

[0075] Hereinafter, the difference between the organic light-emitting display apparatus 1 of FIG. 3 and an organic light-emitting display apparatus 2 of FIG. 6 will be described. FIG. 6 is a cross-sectional view illustrating a periphery area PA corresponding to an edge in which branched openings 218h11b and 218h12b of FIG. 5 are disposed.

[0076] Referring to FIGS. 5 and 6, the organic light-emitting display apparatus 2, according to an exemplary embodiment of the present invention, includes a substrate 210 having a display area DA and a periphery area PA that is located outside of the display area DA. A first insulating layer 218 is disposed in both the display area DA and the periphery area PA. The first insulating layer 218 is disposed over the substrate 210 and has a first opening 218h1 located in the periphery area PA. A first electrode 231 is disposed in the display area DA, over the first insulating layer 218. A first bank 219a is disposed over the first insulating layer 218 in both the display area DA and the periphery area PA. The first bank 219a includes a second opening 219h2, through which the center of the first electrode 231 is exposed. A second bank 219b is disposed over the first insulating layer 218 and is separated from the first bank 219a. The first opening 218h1 is disposed between the first bank 219a and

the second bank **219b**. An intermediate layer **233** is disposed over the first electrode **231**. A second electrode **235** is disposed over the intermediate layer **233** and the first bank **219a**.

[0077] The display area DA may include four corners and four edges which may connect the four corners. For example, the display area DA may have a rectangular shape. However, exemplary embodiments of the present invention are not limited thereto, and the display area DA may have a triangular shape or a polygonal shape such as a pentagonal shape or different polygonal shape.

[0078] A buffer layer **211** may be disposed over the substrate **210** and thin film transistors TFT1. OLEDs **230** are electrically connected to the thin film transistors TFT1. Each of the OLEDs **230** include the first electrode **231**. The intermediate layer includes an EML. The second electrode **215** may be disposed in the display area DA over the buffer layer **211**.

[0079] Each of the thin film transistors TFT1 may include a semiconductor layer **222**, a gate electrode **224**, a source electrode **226S**, and a drain electrode **226D**. A gate insulating layer **213** may be disposed between the semiconductor layer **222** and the gate electrode **224**, and a second insulating layer **215** may be disposed over the gate electrode **224**. The gate insulating layer **213** and the second insulating layer **215** may each include inorganic materials. The gate insulating layer **213** and the second insulating layer **215** may each be disposed within both the display area DA and the periphery area PA.

[0080] The first insulating layer **218** may be disposed over the thin film transistors TFT1 in the display area DA and the periphery area PA. The first insulating layer **218** may include the first opening **218h1**, which is located in the periphery area PA and through which the second insulating layer **215** is exposed. The first opening **218h1** may encompass the display area DA and may form a closed loop.

[0081] The first opening **218h1** includes a main opening **218h1a** and a plurality of branched openings **218h11b** and **218h12b** branched from the main opening **218h1a**. The main opening **218h1a** may be disposed adjacent to each of the four corners. Each of the branched openings **218h11b** and **218h12b** may be disposed at the four edges. However, exemplary embodiments of the present invention are not limited thereto, and the branched openings **218h11b** and **218h12b** may be located in at least two of the four edges.

[0082] Because the dead space of The periphery area PA corresponding to the corners of the display area DA is narrow, it may be difficult to form a plurality of openings in the first insulating layer **218**. However, because the dead space of the periphery area PA corresponding to the edges of the display area DA is wide, a sufficiently large space in which a plurality of openings may be formed, may be secured. Thus, as illustrated in FIG. 5, one main opening **218h1a** may be formed in the corners, and the plurality of branched openings **218h11b** and **218h12b** branched from the main opening **218h1a** may be disposed in the edges so that an impurity may be prevented from being introduced into the display area DA.

[0083] The first insulating layer **218** may be divided by the first opening **218h1** into a first area **218a**, a second area **218b**, and a third area **218c**. The third area **218c** may be surrounded by the branched openings **218h11b** and **218h12b**. For example, the third area **218c** may have an island shape. The first electrode **231** may be disposed in the

display area DA over the first insulating layer **218**, and a conductive layer **250** may be disposed in the periphery area PA. The conductive layer **250** may include a plurality of third openings **250h3**. The plurality of third openings **250h3** may be located in the first area **218a**, the second area **218b** and the third area **218c** of the first insulating layer **218**.

[0084] The first bank **219a** may be disposed over the first insulating layer **218** within both the display area DA and the periphery area PA. The second bank **219b** may be disposed over the first insulating layer **218** in the periphery area PA. The first bank **219a** includes a second opening **219h2** through which the center of the first electrode **231** is exposed. The first bank **219a** may be divided into a plurality of areas **219a1**, **219a2**, and **219a3** in the periphery area PA. The second bank **219b** may be separated from the first bank **219a**. The branched openings **218h11b** and **218h12b** are disposed between the first bank **219a** and the second bank **219b**. The third bank **219c** may be separated from both the first bank **219a** and the second bank **219b**, between the plurality of branched openings **218h11b** and **218h12b**. For example, the first bank **219a**, the second bank **219b**, and the third bank **219c** may each be disposed in a first area **218a**, a second area **218b**, and a third area **218c** of the first insulating layer **218**, respectively. Each of a distance d1 (from an edge of the first bank **219a** to the branched opening **218h11b**) and a distance d2 (from an edge of the third bank **219c** to the branched opening **218h11b**) may be about 4 μm or more so that the first through third banks **219a**, **219b** and **219c** may be completely separated from one another. A width d3 of the branched opening **218h11b** may be about 7 μm or more. For example, a distance between the first bank **219a** and the third bank **219c** may be about 15 μm or more.

[0085] Similarly, each of a distance d4 (from an edge of the third bank **219c** to the branched opening **218h12b**) and a distance d5 (from an edge of the second bank **219b** to the branched opening **218h12b**) may be about 4 μm or more. A width d6 of the branched opening **218h12b** may be about 7 μm or more. For example, a distance between the second bank **219b** and the third bank **219c** may be about 15 μm or more.

[0086] The first bank **219a**, the second bank **219b**, and the third bank **219c** may cover at least a part of the conductive layer **250** in the periphery area PA and might not be disposed in the branched openings **218h11b** and **218h12b**. The conductive layer **250** may include a plurality of third openings **250h3**.

[0087] The intermediate layer **233** including an EML may be disposed over the first electrode **231**. The second electrode **235** may be disposed over the intermediate layer **233**. The second electrode **235** may be disposed at a top portion of the intermediate layer **233** and a top portion of the first bank **219a**. The second electrode **235** might not be disposed in the first opening **218h1** and might not be disposed at a top portion of the second bank **219b** or a top portion of the third bank **219c**. The second electrode **235** may contact the conductive layer **250** in regions between the plurality of areas **219a1**, **219a2**, and **219a3** of the first bank **219a**. The conductive layer **250** may be a power line for supplying power to the second electrode **235** or a connection line for connecting the power line for supplying power to the second electrode **235**.

[0088] A capping layer **240** for increasing light efficiency of the organic light-emitting display apparatus **2** and including an organic material may be disposed over the second

electrode 235. An encapsulation layer 260 covers the OLED 230 and protects the OLED 230 from moisture or oxygen from the outside. The encapsulation layer 260 may be disposed over the capping layer 240. The encapsulation layer 260 may cover the display area DA and may extend up to the periphery area PA. The encapsulation layer 260 may include a first inorganic layer 261, an organic layer 263, and a second inorganic layer 265, as illustrated in FIG. 6.

[0089] The first inorganic layer 261 may cover the capping layer 240 and may include a silicon oxide, a silicon nitride and/or a silicon oxynitride. Other layers including an LiF layer may be disposed between the first inorganic layer 261 and the capping layer 240, as needed. Because the first inorganic layer 261 is formed along a lower structure, a top surface of the first inorganic layer 261 might not be flat, as illustrated in FIG. 6. The organic layer 263 may cover the first inorganic layer 261, and a top surface of the organic layer 263 may be substantially flat. The organic layer 263 may include polyethylene terephthalate (PET), polyethylene naphthalate (PEN), poly carbonite (PC), polyimide (PI), polyethylene sulfonate, polyoxymethylene, polyarylates (PAR), and hexamethyldisiloxane. The second inorganic layer 265 may cover the organic layer 263 and may include a silicon oxide, a silicon nitride and/or a silicon oxynitride. Although not shown, the second inorganic layer 265 may contact the first inorganic layer 261 in an edge region of the organic light-emitting display apparatus 2 so as to protect the organic layer 263 from exposure to the outside.

[0090] In this way, the encapsulation layer 260 includes the first inorganic layer 261, the organic layer 263, and the second inorganic layer 265. Thus, through this multi-layered structure, even though cracks occur in the encapsulation layer 260, these cracks might not be connected between the first inorganic layer 261 and the organic layer 263 or between the organic layer 263 and the second inorganic layer 265. Thus, a path in which moisture or oxygen from the outside penetrates into the display area DA, may be prevented from being formed, or formation thereof may be reduced.

[0091] FIG. 7 is a cross-sectional view schematically illustrating a part of an organic light-emitting display apparatus 3 according to an exemplary embodiment of the present invention. Because the remaining configurations of the organic light-emitting display apparatus 3 of FIG. 7 except for a first insulating layer 318 and a conductive layer 350 may be substantially the same as those of the organic light-emitting display apparatus 1 of FIG. 3 or the organic light-emitting display apparatus 2 of FIG. 6, hereinafter, only the first insulating layer 318 and the conductive layer 350 will be described, and it is to be assumed that all other elements not described herein are substantially the same as corresponding elements described with reference to FIG. 3 or 6.

[0092] Referring to FIG. 7, the organic light-emitting display apparatus 3 according to an exemplary embodiment of the present invention includes the first insulating layer 318 disposed in the display area DA and the periphery area PA. The first insulating layer 318 may include a first opening 318h1 located in the periphery area PA. The first opening 318h1 may surround the display area DA and may include a main opening 318h1a disposed in the periphery area PA corresponding to a corner of the display area DA and three branched openings 318h11b, 318h12b, and 318h13b dis-

posed in the periphery area PA corresponding to an edge of the display area DA and branched from the main opening 318h1a.

[0093] In FIG. 7, the three branched openings 318h11b, 318h12b, and 318h13b are located in one edge of the display area DA. However, embodiments are not limited thereto. For example, the three branched openings 318h11b, 318h12b, and 318h13b may be located in two or more edges. The first insulating layer 318 may be divided by the three branched openings 318h11b, 318h12b, and 318h13b into a first area 318a, a second area 318b, a third area 318c, and a fourth area 318d, which are separated from one another. The third area 318c and the fourth area 318d may be surrounded by the branched openings 318h11b, 318h12b, and 318h13b. For example, each of the third area 318c and the fourth area 318d may have an island shape.

[0094] In the organic light-emitting display apparatus 3 of FIG. 7, the three branched openings 318h11b, 318h12b, and 318h13b are disposed in one edge of the display area DA. Thus, gas or moisture introduced from the outside or generated from layers disposed outside the first opening 318h1 and formed of organic materials may be more effectively blocked so that the quality of an image formed in the organic light-emitting display apparatus 5 may be prevented from being deteriorated or deterioration may be reduced.

[0095] In the organic light-emitting display apparatuses 1, 2, and 3 according to the above-described embodiments, the first insulating layers 118, 218, and 318 including the first openings 118h1, 218h1, and 318h1 are disposed in the periphery area PA, and an introduction path of impurities that may be introduced into the first openings 118h1, 218h1, and 318h1 from outside of the first openings 118h1, 218h1, and 318h1 may be effectively blocked so that the quality of an image formed in each of the organic light-emitting display apparatuses 1, 2, and 3 may be prevented from being deteriorated or deterioration may be reduced.

[0096] As described above, according to the one or more exemplary embodiments of the present invention, an organic light-emitting display apparatus may prevent the quality of an image from being deteriorated, or may reduce an extent to which quality is deteriorated, as a result of contamination that might occur during a manufacturing process or in subsequent use.

[0097] While exemplary embodiments of the present invention have been described above with reference to the figures, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope of the invention.

What is claimed is:

1. An organic light-emitting display apparatus, comprising:
 - a substrate including a display area in a center thereof and a non-display area surrounding the display area;
 - a first bank disposed on the substrate and having an OLED and a plurality of openings that correspond to a plurality of sub-pixels;
 - a second bank separated from the first bank and disposed entirely within the non-display area; and
 - an insulating layer covering the first bank and the second bank and having an opening disposed between the first bank and the second bank such that the opening separates the first bank from the second bank.

2. The organic light-emitting display apparatus of claim 1, further comprising a conductive layer disposed over the insulating layer and covering the opening that is disposed between the first bank and the second bank, the conductive layer being at least partially exposed within the non-display area.

3. The organic light-emitting display apparatus of claim 1, wherein the first bank and the second bank include a same organic material as the insulating layer.

4. The organic light-emitting display apparatus of claim 1, further including a first electrode disposed within the display area and overlapping the insulation layer therein.

5. The organic light-emitting display apparatus of claim 4, wherein a center of the first electrode is exposed through an opening in the first bank.

6. The organic light-emitting display apparatus of claim 1, further including an intermediate layer, disposed over the first electrode, and a second electrode, the second electrode disposed over the intermediate layer and the first bank.

* * * * *

专利名称(译)	具有受保护发光层的有机发光显示装置		
公开(公告)号	US20190259820A1	公开(公告)日	2019-08-22
申请号	US16/404464	申请日	2019-05-06
[标]申请(专利权)人(译)	三星显示有限公司		
申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
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IPC分类号	H01L27/32 H01L51/52		
CPC分类号	H01L27/3246 H01L27/3276 H01L51/5253 H01L27/3262 H01L51/5237 H01L51/5203 H01L51/5246 H01L27/3244		
优先权	1020160035546 2016-03-24 KR		
其他公开文献	US10714550		
外部链接	Espacenet USPTO		

摘要(译)

有机发光显示装置防止由于有机发光层的污染而使其上显示的图像的质量劣化。显示装置包括具有显示区域和周边区域的基板。设置在衬底上的第一绝缘层在外围区域中具有第一开口。第一电极设置在显示区域内，在第一绝缘层上。第一隔堤设置在第一绝缘层上方并具有第二开口，第一电极的中心通过第二开口暴露。第二隔堤设置在第一绝缘层上方并与第一隔堤分离。第一开口设置在第一排和第二排之间。中间层设置在第一电极上。第二电极设置在中间层和第一隔堤之上。

